## NSN 5962-01-314-6469

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View Online at https://aerobasegroup.com/nsn/5962-01-314-6469

Overall Length:
0.840 inches
Overall Height:
0.400 inches
Overall Width:
0.320 inches
Body Length:
0.840 inches
Body Width:
0.310 inches
Body Height:
0.185 inches
Maximum Power Dissipation Rating:
739.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
5805-01-187-9399
Features Provided:
Bipolar and burn in and hermetically sealed and programmed and schottky and w/active pull-up
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
10 input
Case Outline Source And Designator:
D-2 mil-m-38510
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
7.0 volts power source
Memory Device Type:
Rom
Test Data Document:
96906-mil-std-883  standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:

16 printed circuit

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Shelf Life:

N/a

**Unit Of Measure:** 

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Demilitarization:

Yes - demil/mli

Fiig:

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